

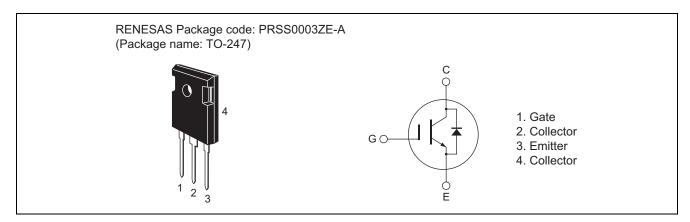
RJH60M0DPQ-E0

600V - 22A - IGBT Application: Inverter R07DS1085EJ0200 Rev.2.00 Jun 13, 2013

Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)}=1.6~V$ typ. (at $I_C=22~A,~V_{GE}=15~V,~Ta=25^{\circ}C$)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching $t_f = 55 \text{ ns typ. (at $V_{CC} = 300$ V, $V_{GE} = 15$ V, $I_C = 22$ A, $Rg = 5$ Ω, $Ta = 25^{\circ}$C, inductive load)}$

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	I _C	45	А
	Tc = 100°C	I _C	22	А
Collector peak current		I _C (peak) Note1	66	А
Collector to emitter diode forward current		I _{DF}	22	А
Collector to emitter diode forward peak current		I _{DF} (peak) Note1	66	А
Collector dissipation		P _C Note2	116.8	W
Junction to case thermal resistance (IGBT)		θj-c ^{Note2}	1.07	°C/W
Junction to case thermal resistance (Diode)		θj-cd Note2	2.3	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

 $di_F/dt = 100 A/\mu s$

μС

Α

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μΑ	$V_{CE} = 600 \text{ V}, V_{GE} = 0$
Gate to emitter leak current	I _{GES}		_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	5	_	7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.8	2.3	V	$I_C = 22 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
	V _{CE(sat)}	1	2.4	_	V	$I_C = 45 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies	_	1050	_	pF	V _{CE} = 25 V V _{GE} = 0 f = 1 MHz
Output capacitance	Coes	_	75	_	pF	
Reverse transfer capacitance	Cres	_	45	_	pF	
Total gate charge	Qg	_	65	_	nC	$V_{GE} = 15 \text{ V}$ $V_{CE} = 300 \text{ V}$ $I_{C} = 22 \text{ A}$
Gate to emitter charge	Qge	_	10	_	nC	
Gate to collector charge	Qgc	_	39	_	nC	
Turn-on delay time	t _{d(on)}	_	40	_	ns	$V_{CC} = 300 \text{ V}$ $V_{GE} = 15 \text{ V}$ $I_{C} = 22 \text{ A}$ $Rg = 5 \Omega$ Inductive load
Rise time	t _r	_	25	_	ns	
Turn-off delay time	t _{d(off)}	_	90	_	ns	
Fall time	t _f	_	55	_	ns	
Turn-on energy	Eon	_	0.48	_	mJ	
Turn-off energy	E _{off}	_	0.38	_	mJ	
Total switching energy	E _{total}	_	0.86	_	mJ	
Short circuit withstand time	t _{sc}	6	8	_	μs	Tc = 100 °C
						$V_{CC} \le 360 \text{ V}, V_{GE} = 15 \text{ V}$
FRD Forward voltage	V _F	_	1.4	1.9	V	I _F = 22 A ^{Note3}
FRD reverse recovery time	t _{rr}	_	100	_	ns	I _F = 22 A

0.14

4.4

 Q_{rr}

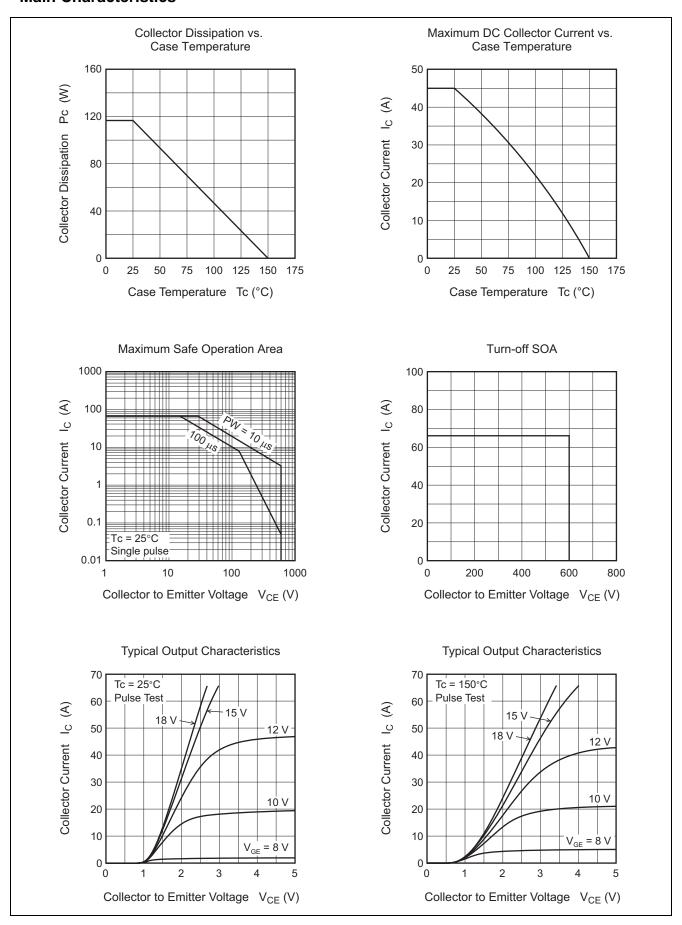
 $I_{rr} \\$

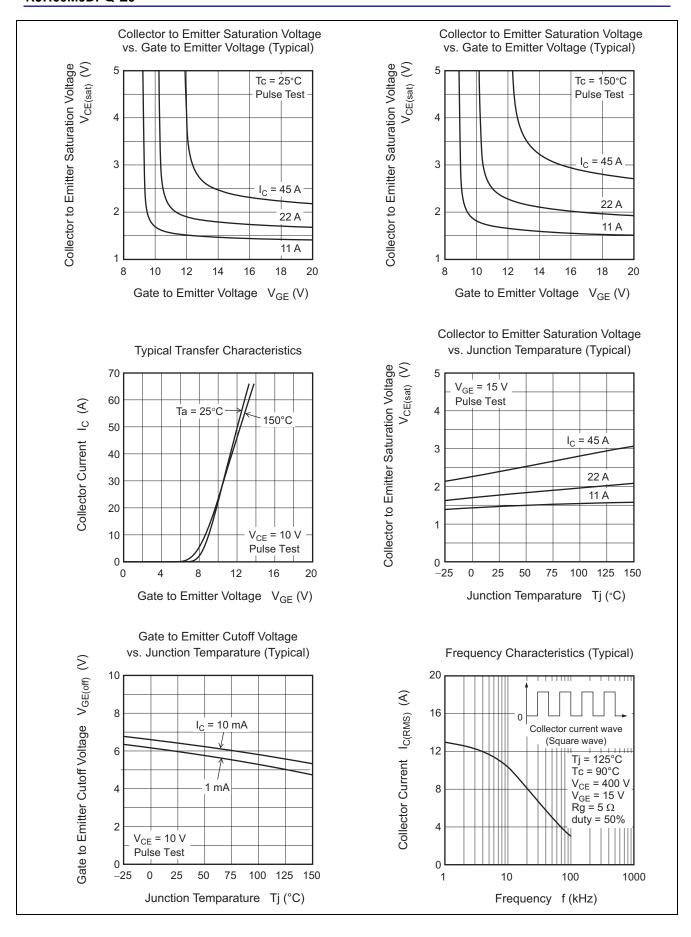
Notes: 3. Pulse test.

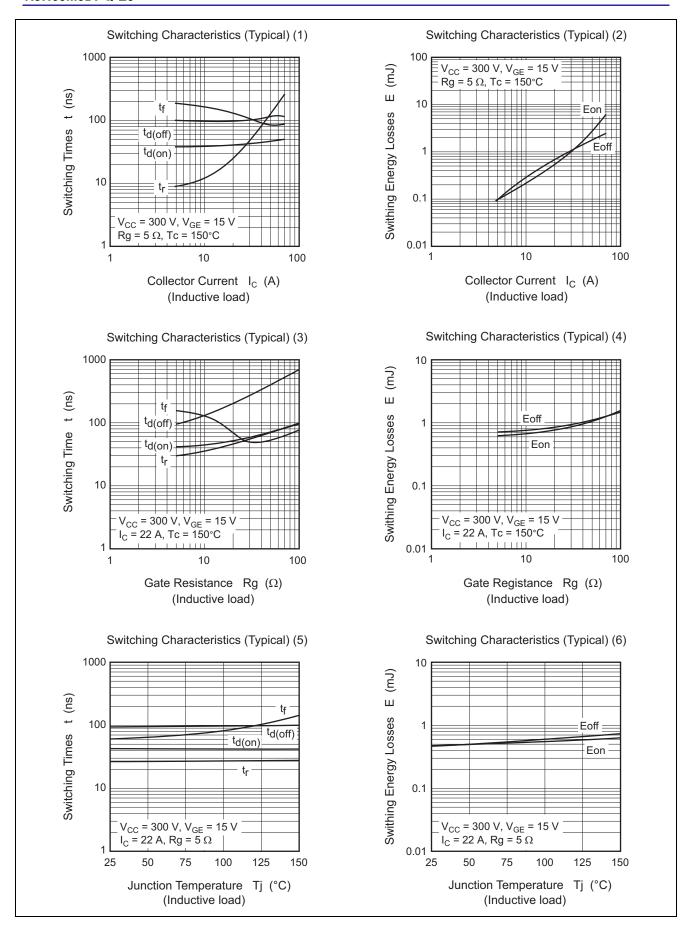
FRD reverse recovery charge

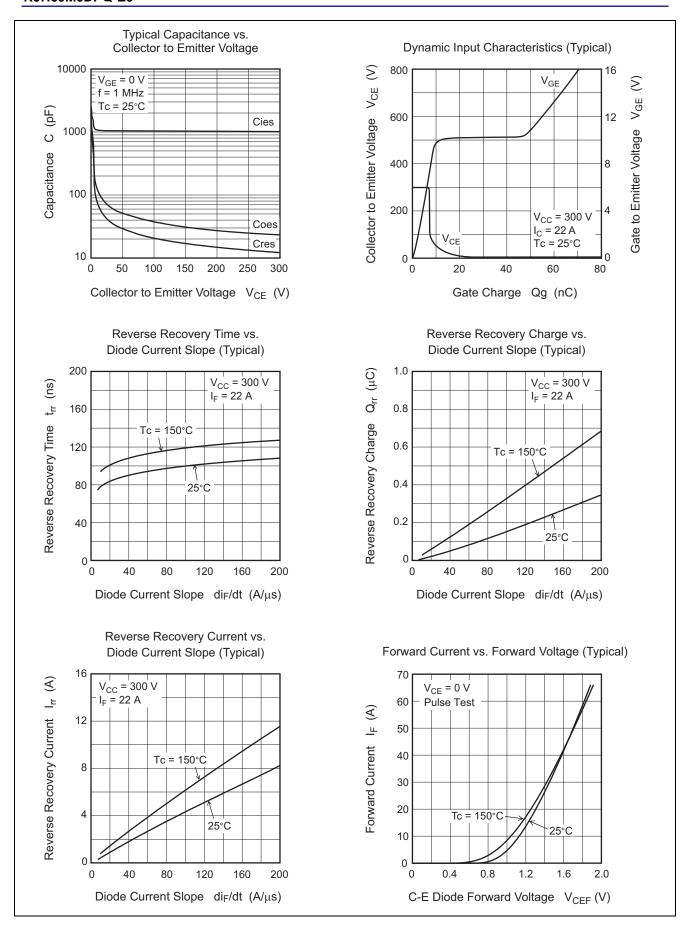
FRD peak reverse recovery current

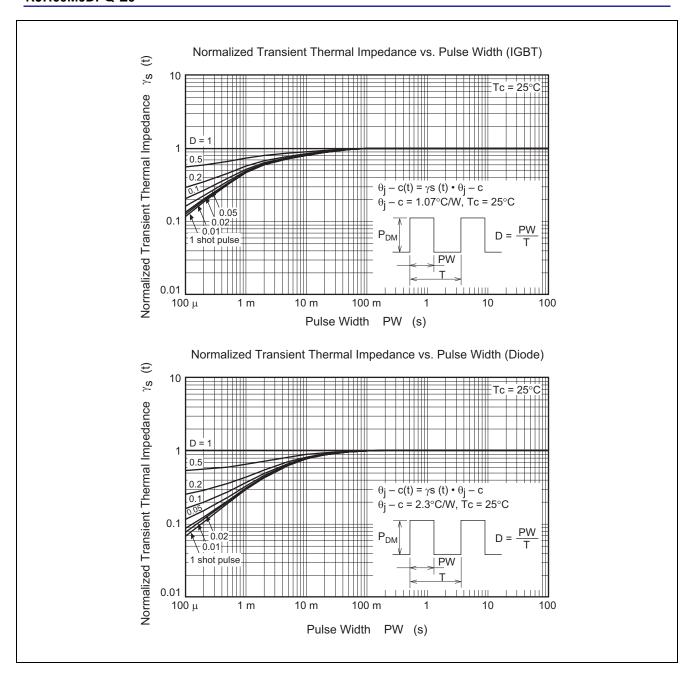
Main Characteristics

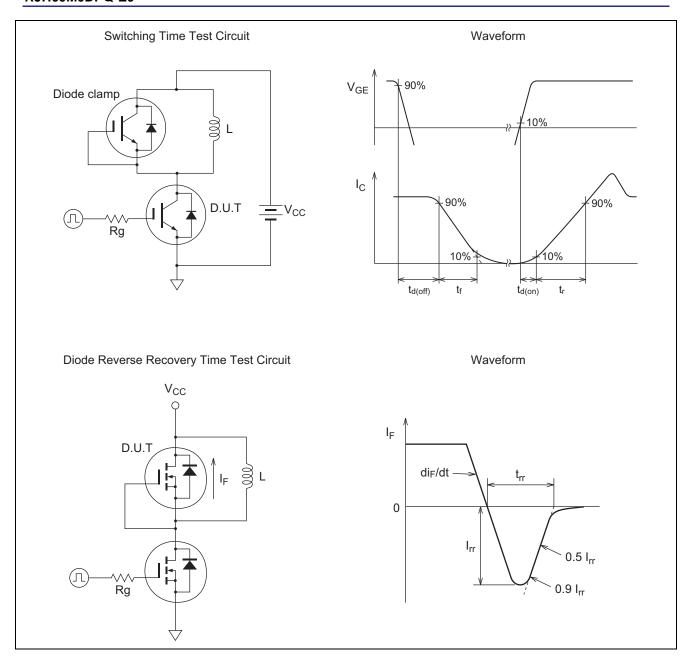




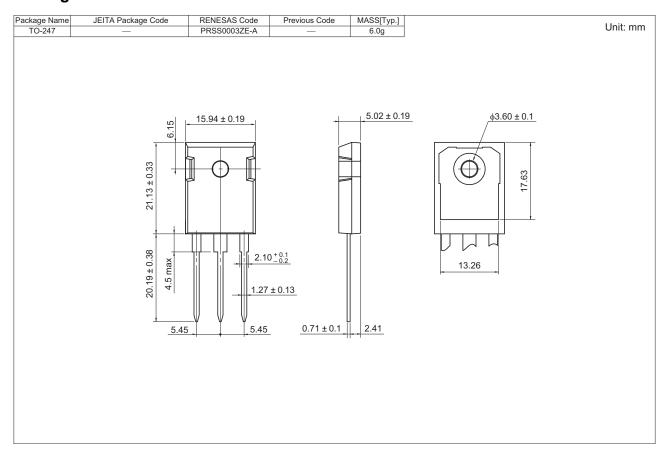








Package Dimension



Ordering Information

Orderable Part No.	Quantity	Shipping Container	
RJH60M0DPQ-E0#T2	450 pcs	Tube	

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Renesas Electronics America Inc. 2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Milliboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd. 7th Floor, Quantum Plaza, No.27 ZhiChunLu Ha Tel: +86-10-8235-1155, Fax: +86-10-8235-7679 i. nunLu Haidian District. Beiiing 100083. P.R.China

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2868-9318, Fax: +852 2869-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

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Renesas Electronics Malaysia Sdn.Bhd. Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

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